



10G InGaAs APD Photodiode TIA ROSA-FC Package

Description

A 10 Gb/s InGaAs APD photodiode packaged with a transimpedance amplifier (TIA). This device is packaged in a TO-Can with FC bulkhead receptacle. It comes configured with a Flex PCB. Offering flat response and a broad temperature operating range. This device can be easily soldered to a PCB for mechanically rigidity.

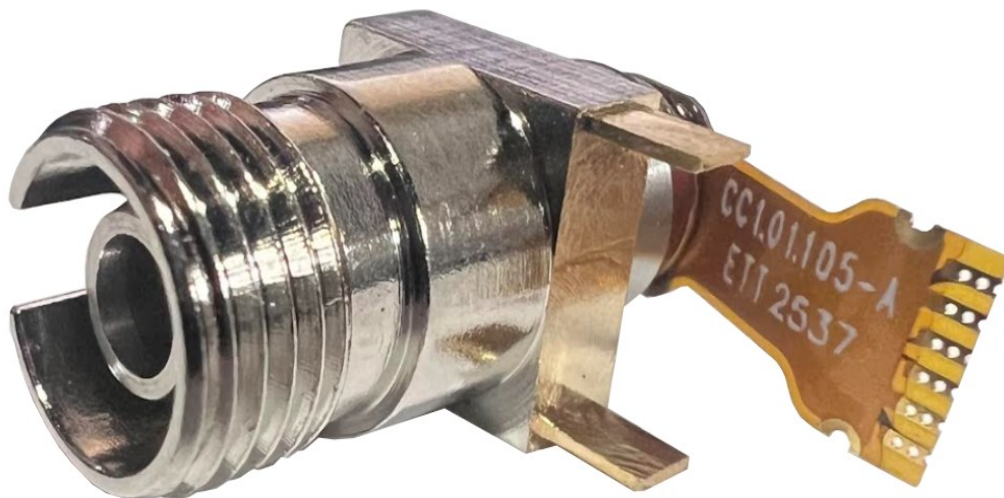
Features

- TO-Can Package
- FC-Receptacle
- 10 Gbps
- Wide temperature operating range
- Received signal strength indicator
- TIA Built in
- 4K Ohm Transimpedance Gain
- PCB solderable mount
- -27 dBm sensitivity



Applications

- 5G
- RF over Fiber (RToF)



Photodiode Electro-Optical Characteristics ($T_{op} 23 \pm 3^{\circ}\text{C}$, unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Supply Voltage	V_{cc}	2.9	3.3	3.6	V	
Supply Current	I_{cc}	-	26	35	mA	$V_{cc} = 3.3 \text{ V}$
Response Spectrum	λ	1260	-	1610	nm	$V_{cc} = 3.3 \text{ V}$
Bandwidth	BW	-	8	-	GHz	-3 dB bandwidth
Saturation	Sat	-	3	-	dBm	$V_{cc} = 3.3 \text{ V}$
Sensitivity	Sen	-	-30	-27	dBm	10.30 Gbps, 1310 nm, ER = 4.5 dB, BER = 10^{-12}
Optical Return Loss	ORL	-	-	-28	dB	CW = 1310 nm
RSSI Offset Current	I_{RSS}	-	-	100	nA	$V_{cc} = 3.3 \text{ V}$
Responsivity	R	0.7	0.8	-	A/W	1310 nm, 50 % VBR, M=2, Pin -20 dBm
Dark Current	I_d		30	100	nA	VBr
Output Impedance	Z_o	-	100	-		Differential
Maximum Output Voltage	V_o	-	300	-	mV _{p-p}	Differential
Low Frequency Cutoff	F_{low}	-	10	-	KHz	

Photodiode Absolute Maximum Ratings

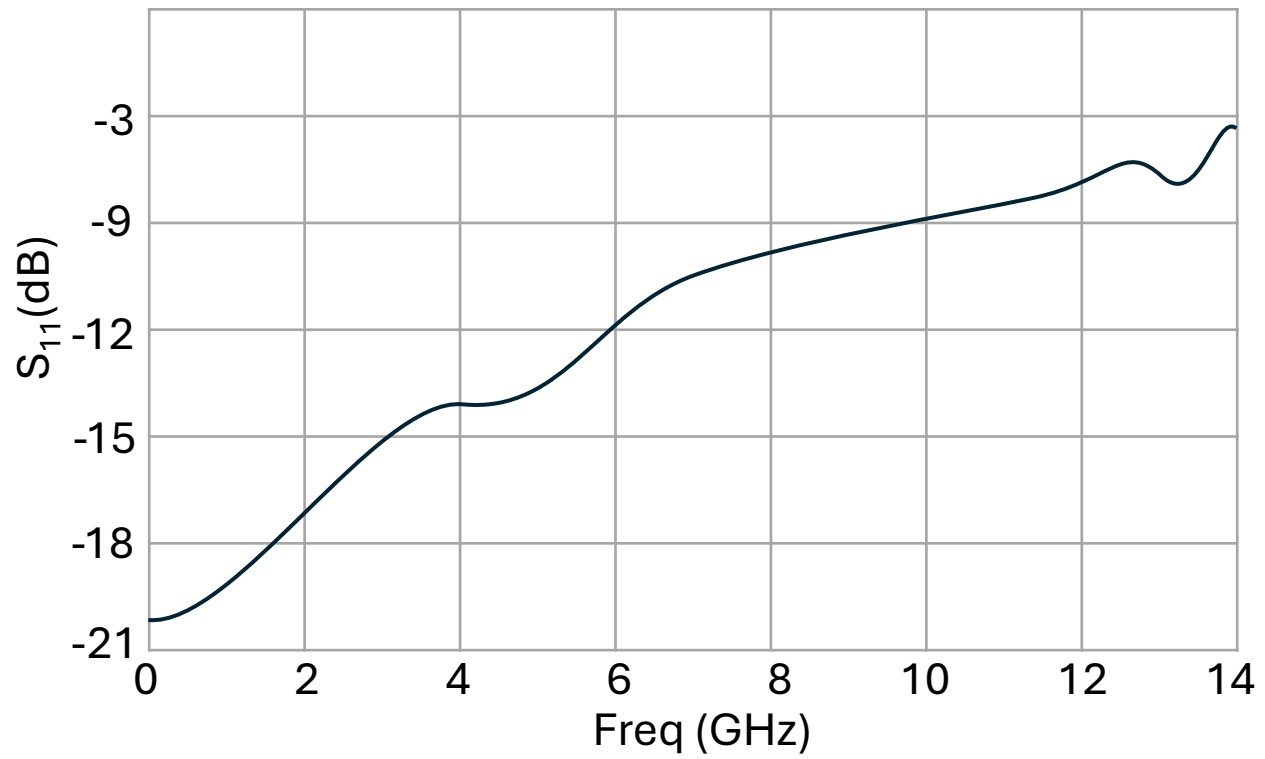
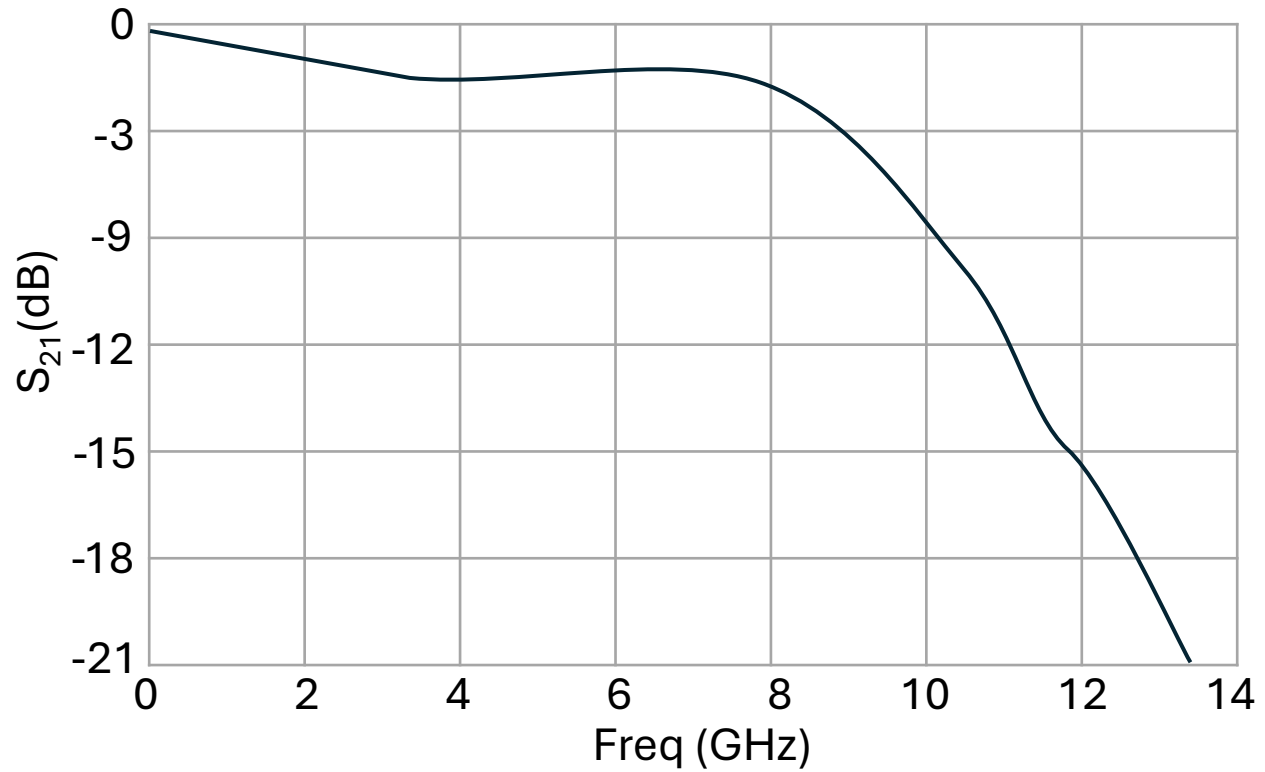
Parameter	Symbol	Condition	Min.	Max.	Unit
Voltage	V	-	-	3.6	V
Vapd	V	-	-	40	V
Input Optical Power	P_{in}	-	-	5	dBm
Storage Temperature	T_{stg}	-	-40	90	$^{\circ}\text{C}$
Storage Humidity	H_{stg}	-	-	85	% r.H.
Operating Temperature	T_{op}	-	-40	85	$^{\circ}\text{C}$
Soldering Temperature	T_{st}	10 sec	-	260	$^{\circ}\text{C}$
ESD Susceptibility		HBM	100	-	V

Operating at maximum operating specs for prolong periods of time will damage the device.

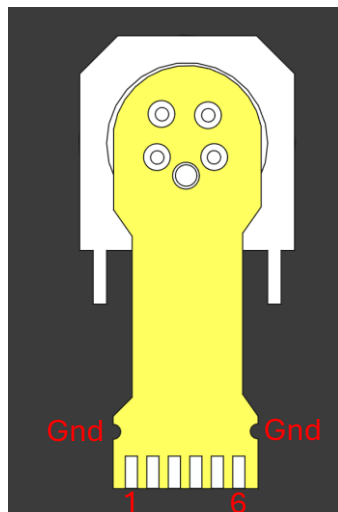


Typical Performance Curves (Top 23°C, 801 PTs, 16 AVGs, 1.5% smoothing)

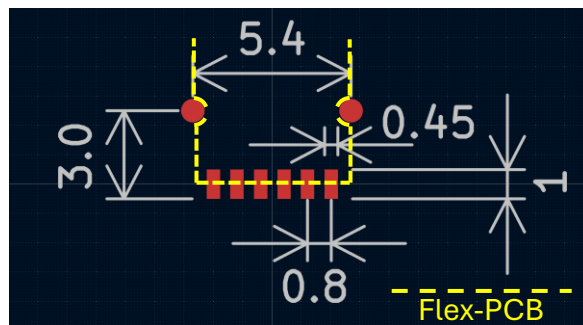
RF performance dependent on PCB design and optimization. Data shown for Rogers® RO3003 with Ground-backed Co-planar waveguide (GB-CPW). The GB-CPW was de-embedded. Single ended measurement, port two is terminated with 50 Ohm load



Device Pinout

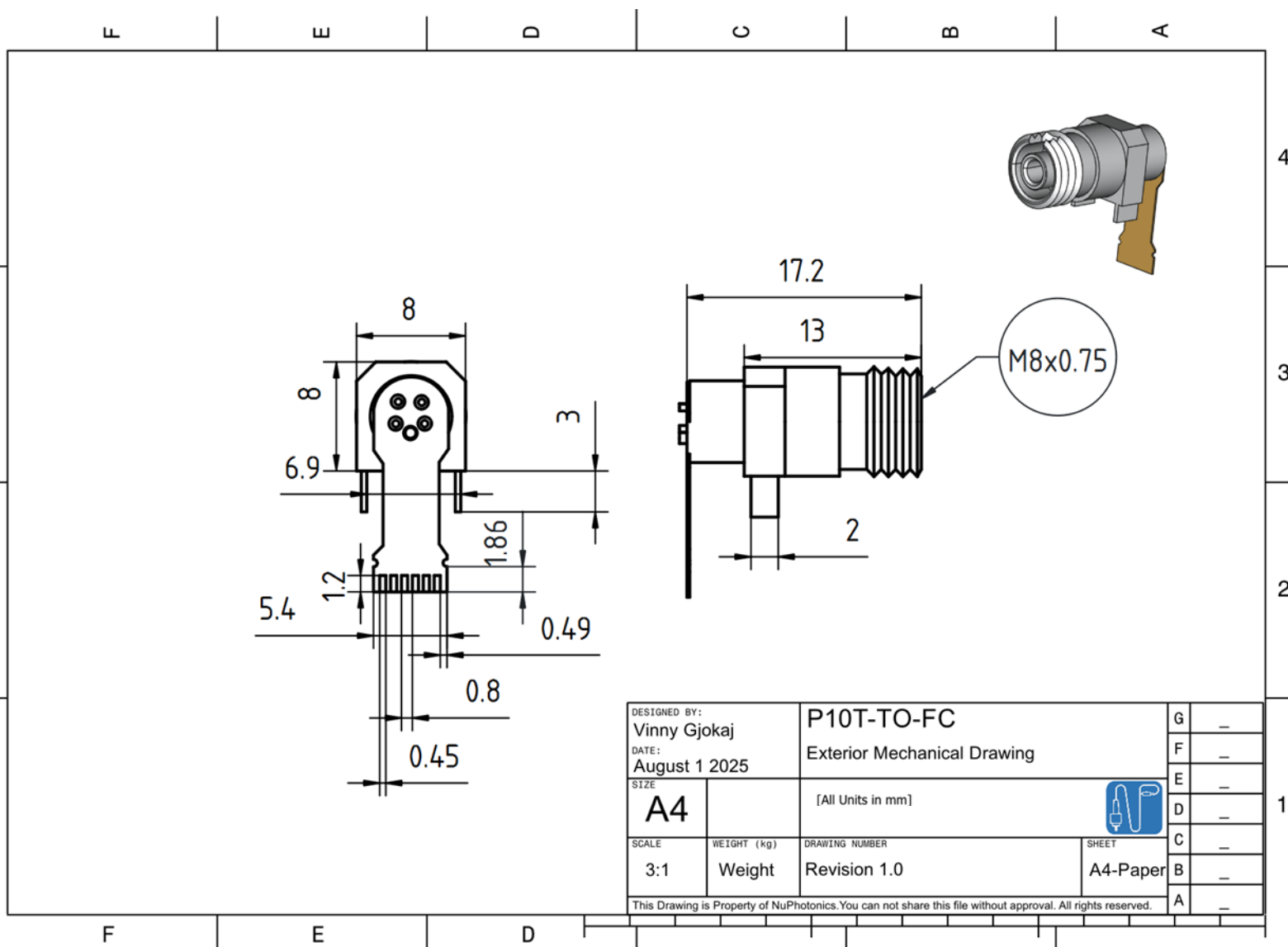


Pin	Function
1	VCC
2	Gnd
3	Dout +
4	Dout -
5	Gnd
6	Vapd



Recommended PCB Footprint (all units in mm)

Mechanical Drawing



Device dimensions are subject to change without notice.



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Revision History

1.0 – September 2025 – Initial Release